# 2N3906

# **General Purpose Transistors**

# **PNP Silicon**

#### **Features**

• Pb-Free Packages are Available\*



Rating	Symbol	Value	Unit
Collector - Emitter Voltage	V <sub>CEO</sub>	40	Vdc
Collector - Base Voltage	V <sub>CBO</sub>	40	Vdc
Emitter – Base Voltage	V <sub>EBO</sub>	5.0	Vdc
Collector Current - Continuous	Ic	200	mAdc
Total Device Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	625 5.0	mW mW/°C
Total Power Dissipation @ T <sub>A</sub> = 60°C	P <sub>D</sub>	250	mW
Total Device Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	P <sub>D</sub>	1.5 12	W mW/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

# THERMAL CHARACTERISTICS (Note 1)

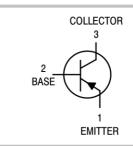
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	83.3	°C/W

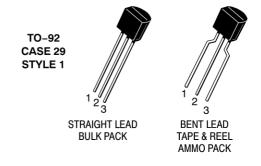
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Indicates Data in addition to JEDEC Requirements.

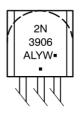


http://onsemi.com





#### **MARKING DIAGRAM**



A = Assembly Location

= Wafer Lot

Y = Year

W = Work Week

= Pb-Free Package

(Note: Microdot may be in either location)

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 3 of this data sheet.

<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# 2N3906

# **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

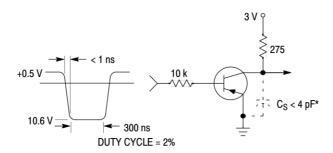
	Chara	Symbol	Min	Max	Unit	
OFF CHARACTERIS	TICS				•	•
Collector - Emitter Bre	eakdown Voltage (No	ote 2) $(I_C = 1.0 \text{ mAdc}, I_B = 0)$	V <sub>(BR)CEO</sub>	40	_	Vdc
Collector - Base Break	kdown Voltage	$(I_{C} = 10 \mu Adc, I_{E} = 0)$	V <sub>(BR)CBO</sub>	40	-	Vdc
Emitter - Base Breakd	lown Voltage	$(I_E = 10 \mu Adc, I_C = 0)$	V <sub>(BR)EBO</sub>	5.0	-	Vdc
Base Cutoff Current		(V <sub>CE</sub> = 30 Vdc, V <sub>EB</sub> = 3.0 Vdc)	I <sub>BL</sub>	_	50	nAdc
Collector Cutoff Curre	ent	$(V_{CE} = 30 \text{ Vdc}, V_{EB} = 3.0 \text{ Vdc})$	I <sub>CEX</sub>	-	50	nAdc
ON CHARACTERIST	ICS (Note 2)			,		
DC Current Gain			h <sub>FE</sub>	60 80 100 60 30	- 300 - -	-
Collector - Emitter Sat	turation Voltage	$(I_C = 10 \text{ mAdc}, I_B = 1.0 \text{ mAdc})$ $(I_C = 50 \text{ mAdc}, I_B = 5.0 \text{ mAdc})$	V <sub>CE(sat)</sub>		0.25 0.4	Vdc
Base – Emitter Saturat	tion Voltage	$(I_C = 10 \text{ mAdc}, I_B = 1.0 \text{ mAdc})$ $(I_C = 50 \text{ mAdc}, I_B = 5.0 \text{ mAdc})$	V <sub>BE(sat)</sub>	0.65	0.85 0.95	Vdc
SMALL-SIGNAL CH	ARACTERISTICS			,	,	
Current - Gain - Band	lwidth Product	(I <sub>C</sub> = 10 mAdc, V <sub>CE</sub> = 20 Vdc, f = 100 MHz)	f <sub>T</sub>	250	-	MHz
Output Capacitance		$(V_{CB} = 5.0 \text{ Vdc}, I_E = 0, f = 1.0 \text{ MHz})$	C <sub>obo</sub>	_	4.5	pF
Input Capacitance		$(V_{EB} = 0.5 \text{ Vdc}, I_{C} = 0, f = 1.0 \text{ MHz})$	C <sub>ibo</sub>	_	10	pF
Input Impedance		$(I_C = 1.0 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ kHz})$	h <sub>ie</sub>	2.0	12	kΩ
Voltage Feedback Ra	tio	$(I_C = 1.0 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ kHz})$	h <sub>re</sub>	0.1	10	X 10 <sup>-4</sup>
Small-Signal Current	Gain	$(I_C = 1.0 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ kHz})$	h <sub>fe</sub>	100	400	_
Output Admittance		$(I_C = 1.0 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ kHz})$	h <sub>oe</sub>	3.0	60	μmhos
Noise Figure	(I <sub>C</sub> = 100 μA	dc, $V_{CE} = 5.0 \text{ Vdc}$ , $R_S = 1.0 \text{ k}\Omega$ , $f = 1.0 \text{ kHz}$ )	NF	_	4.0	dB
SWITCHING CHARA	CTERISTICS					
Delay Time	Delay Time $(V_{CC} = 3.0 \text{ Vdc}, V_{BE} = 0.5 \text{ Vdc},$		t <sub>d</sub>	_	35	ns
Rise Time	$I_C = 10 \text{ mAdc}, I_{B1}$		t <sub>r</sub>	-	35	ns
Storage Time	(V <sub>CC</sub> = 3.0 Vdc, I <sub>C</sub>	; = 10 mAdc, I <sub>B1</sub> = I <sub>B2</sub> = 1.0 mAdc)	t <sub>s</sub>	-	225	ns
Fall Time	(V <sub>CC</sub> = 3.0 Vdc, I <sub>C</sub>	; = 10 mAdc, I <sub>B1</sub> = I <sub>B2</sub> = 1.0 mAdc)	t <sub>f</sub>	-	75	ns

<sup>2.</sup> Pulse Test: Pulse Width ≤ 300 μs; Duty Cycle ≤ 2%.

#### **ORDERING INFORMATION**

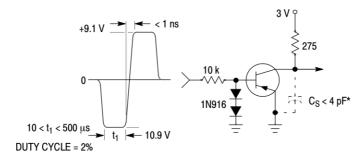
Device	Package	Shipping <sup>†</sup>
2N3906	TO-92	5000 Units / Bulk
2N3906G	TO-92 (Pb-Free)	5000 Units / Bulk
2N3906RL1	TO-92	2000 / Tape & Reel
2N3906RL1G	TO-92 (Pb-Free)	2000 / Tape & Reel
2N3906RLRA	TO-92	2000 / Tape & Reel
2N3906RLRAG	TO-92 (Pb-Free)	2000 / Tape & Reel
2N3906RLRM	TO-92	2000 / Tape & Ammo Box
2N3906RLRMG	TO-92 (Pb-Free)	2000 / Tape & Ammo Box
2N3906RLRP	TO-92	2000 / Tape & Ammo Box
2N3906RLRPG	TO-92 (Pb-Free)	2000 / Tape & Ammo Box

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



<sup>\*</sup> Total shunt capacitance of test jig and connectors

Figure 1. Delay and Rise Time Equivalent Test Circuit



<sup>\*</sup> Total shunt capacitance of test jig and connectors

Figure 2. Storage and Fall Time Equivalent Test Circuit

## 2N3906

## TYPICAL TRANSIENT CHARACTERISTICS

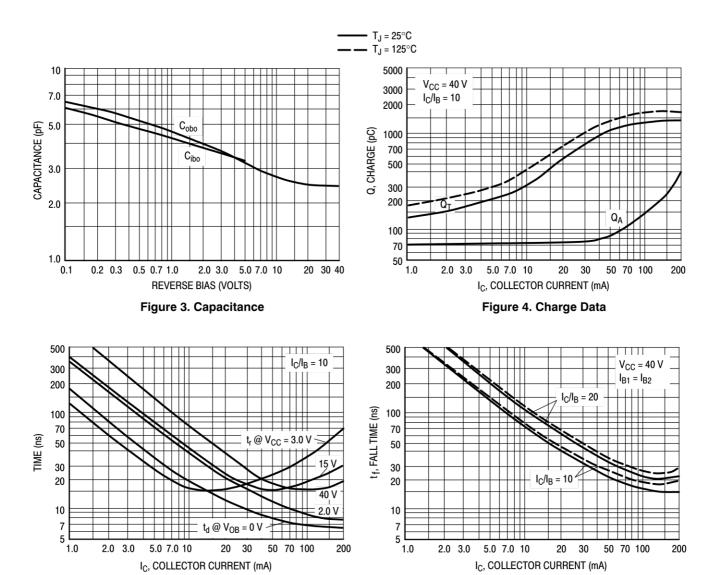
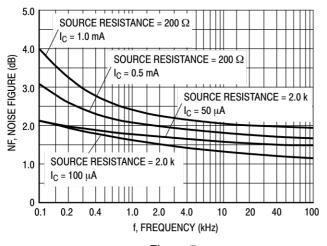


Figure 5. Turn - On Time

Figure 6. Fall Time

# TYPICAL AUDIO SMALL-SIGNAL CHARACTERISTICS **NOISE FIGURE VARIATIONS**

 $(V_{CE} = -5.0 \text{ Vdc}, T_A = 25^{\circ}\text{C}, Bandwidth = 1.0 \text{ Hz})$ 



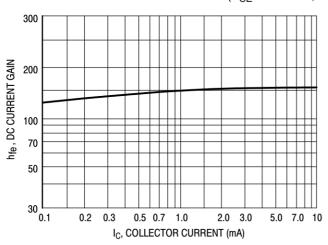
f = 1.0 kHz10 NF, NOISE FIGURE (dB)  $I_C$  = 50  $\mu$ A  $I_C = 100 \mu A$ 0.2 1.0 2.0 4.0 10 20 40 0.1 100 Rq, SOURCE RESISTANCE (k OHMS)

Figure 7.

Figure 8.

## **h PARAMETERS**

 $(V_{CE} = -10 \text{ Vdc}, f = 1.0 \text{ kHz}, T_A = 25^{\circ}\text{C})$ 



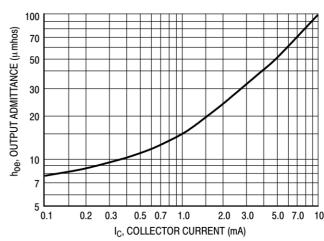
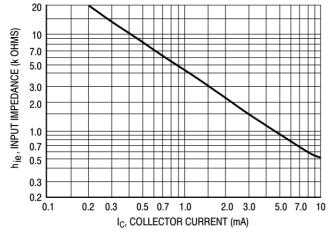


Figure 9. Current Gain

Figure 10. Output Admittance



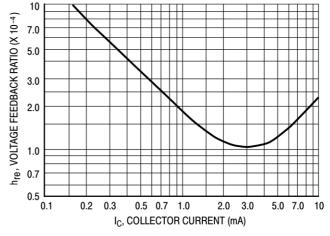


Figure 11. Input Impedance

Figure 12. Voltage Feedback Ratio

#### TYPICAL STATIC CHARACTERISTICS

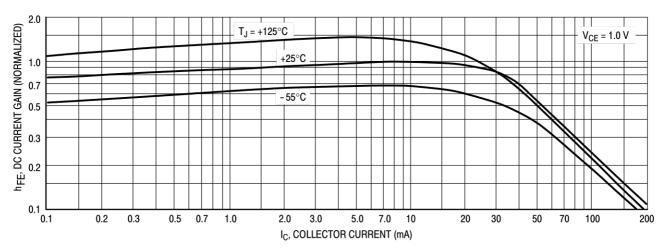


Figure 13. DC Current Gain

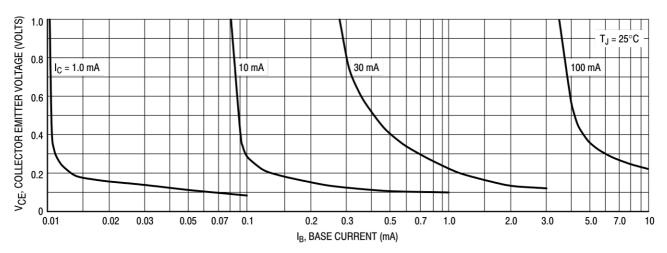


Figure 14. Collector Saturation Region

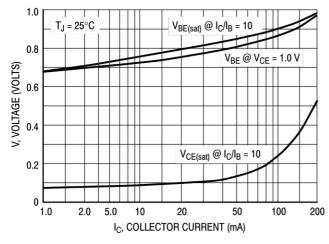


Figure 15. "ON" Voltages

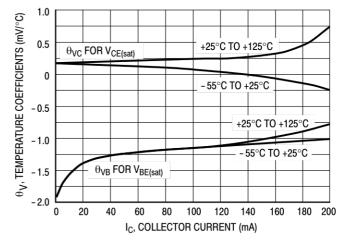
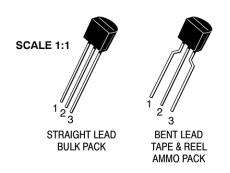


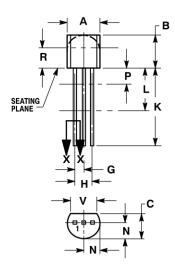
Figure 16. Temperature Coefficients





TO-92 (TO-226) CASE 29-11 **ISSUE AM** 

**DATE 09 MAR 2007** 



STRAIGHT LEAD **BULK PACK** 



#### NOTES:

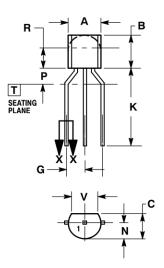
- NOTES:

  1 DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

  2. CONTROLLING DIMENSION: INCH.

  3. CONTROLLED OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
- LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
Р		0.100		2.54
R	0.115		2.93	
٧	0.135		3.43	



**BENT LEAD** TAPE & REEL AMMO PACK



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
  2. CONTROLLING DIMENSION: MILLIMETERS.
  3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
  4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	MILLIMETERS				
DIM	MIN	MAX			
Α	4.45	5.20			
В	4.32	5.33			
С	3.18	4.19			
D	0.40	0.54			
G	2.40	2.80			
J	0.39	0.50			
K	12.70				
N	2.04	2.66			
P	1.50	4.00			
R	2.93				
٧	3.43				

## **STYLES ON PAGE 2**

DOCUMENT NUMBER:	98ASB42022B	Electronic versions are uncontrolle	'	
STATUS:	ON SEMICONDUCTOR STANDARD	accessed directly from the Document versions are uncontrolled except		
NEW STANDARD:		"CONTROLLED COPY" in red.		
DESCRIPTION:	TO-92 (TO-226)		PAGE 1 OF 3	

# TO-92 (TO-226) CASE 29-11 ISSUE AM

# DATE 09 MAR 2007

2.	EMITTER BASE COLLECTOR	STYLE 2: PIN 1. 2. 3.	BASE	STYLE 3: PIN 1. 2. 3.	ANODE	PIN 1. 2.	CATHODE CATHODE ANODE	STYLE 5: PIN 1. 2. 3.	DRAIN
		STYLE 7: PIN 1. 2. 3.	DRAIN	2.		STYLE 9: PIN 1. 2. 3.	EMITTER	2.	CATHODE GATE ANODE
2.	ANODE CATHODE & ANODE	2.	MAIN TERMINAL 1	PIN 1.	ANODE 1 GATE	PIN 1.	EMITTER COLLECTOR		
2.	ANODE	PIN 1. 2.	COLLECTOR BASE	PIN 1. 2.	ANODE CATHODE		GATE ANODE	2.	NOT CONNECTED CATHODE ANODE
PIN 1. 2.	COLLECTOR EMITTER BASE	PIN 1. 2.	SOURCE	PIN 1. 2.	GATE	PIN 1. 2.	EMITTER	STYLE 25: PIN 1. 2. 3.	MT 1
	V <sub>CC</sub>	PIN 1. 2.		PIN 1. 2.	CATHODE	PIN 1. 2.		PIN 1. 2.	DRAIN
		2.		STYLE 33: PIN 1. 2. 3.	RETURN	2.			

DOCUMENT NUMBER:	98ASB42022B	Electronic versions are uncontrolle	
STATUS:	ON SEMICONDUCTOR STANDARD	accessed directly from the Document versions are uncontrolled except	
NEW STANDARD:		"CONTROLLED COPY" in red.	
DESCRIPTION:	TO-92 (TO-226)		PAGE 2 OF 3



DOCUMENT	NU	MB	ER:
98ASB42022	В		

PAGE 3 OF 3

SSUE	REVISION	DATE
AM	ADDED BENT-LEAD TAPE & REEL VERSION. REQ. BY J. SUPINA.	09 MAR 2007

ON Semiconductor and are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

onsemi, Onsemi, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at <a href="www.onsemi.org/linearing/dif-atent-Marking.pdf">www.onsemi.org/linearing/dif-atent-Marking.pdf</a>. Onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any EDA class 3 medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer p

#### ADDITIONAL INFORMATION

**TECHNICAL PUBLICATIONS:** 

Technical Library: www.onsemi.com/design/resources/technical-documentation

onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support

For additional information, please contact your local Sales Representative at www.onsemi.com/support/sales